# MSKSEMI 美森科













ESD

TSS

MOV

GDT

PIFD

# SP0503BAHTG-MS

**Product specification** 





#### **Features**

- 150Watts peak pulse power (tp = 8/20μs)
- Tiny SOT143 package
- Bidirectional configurations
- Solid-state silicon-avalanche technology
- Low clamping voltage
- Low leakage current
- Low capacitance (Cj=30pF typ I/O to I/O.)
- Protection one data/power line to:
- IEC 61000-4-2 ±8kV contact ±15kV air
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 10A (8/20μs)

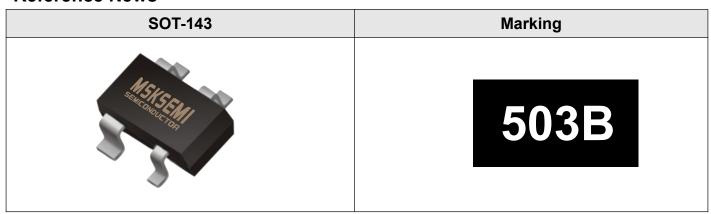
#### **Mechanical Data**

- SOT-143 package
- Molding compound flammability rating: UL 94V-0
- Packaging: Tape and Reel
- RoHS/WEEE Compliant

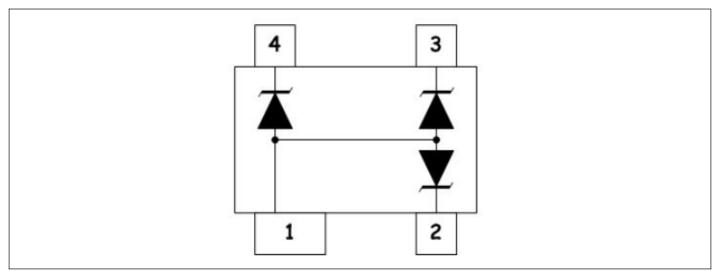
# **Applications**

- USB2.0,
- Ethernet
- Notebooks, Desktops, and Servers
- Video Line Protection

#### **Reference News**



## **Schematic & PIN Configuration**





# **Absolute Maximum Rating**

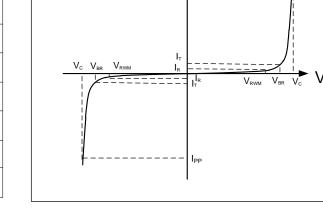
Rating	Symbol	Value	Units
Peak Pulse Power ( t <sub>p</sub> =8/20μs )	P <sub>PP</sub>	150	Watts
Peak Pulse Current ( t <sub>p</sub> =8/20µs ) (note1)	I <sub>pp</sub>	10	A
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	V <sub>ESD</sub>	15 8	kV
Lead Soldering Temperature	TL	260(10seconds)	$^{\circ}$
Junction Temperature	TJ	-55 to + 125	°C
Storage Temperature	$T_{stg}$	-55 to + 125	$^{\circ}$

# Electrical Characteristics (TA = 25°C unless otherwise noted)

Part Number	V <sub>RWM</sub>	<b>V</b> <sub>BR</sub>	h	т <b>V</b> с		Vc		C
Part Number	(V) (V)	(mA)	@1A	(Max)	(@A)	μA (Pf) (Max) (Typ.)	(PT) (Typ.)	
SP0503BAHTG-MS	5	6	1	10	15	10	1	30

# Electrical Parameters (TA = 25°C unless otherwise noted)

Parameter		
Maximum Reverse Peak Pulse Current		
Clamping Voltage @ IPP		
Working Peak Reverse Voltage		
Maximum Reverse Leakage Current @ VRWM		
Breakdown Voltage @ I⊤		
Test Current		



Note:  $8/20 \mu s$  pulse waveform.



## **Typical Characteristics**

Figure 1: Peak Pulse Power vs. Pulse Time

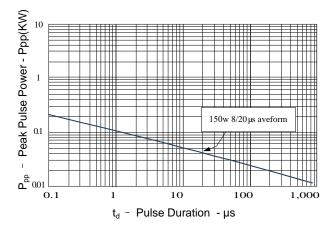


Figure 2: Power Derating Curve

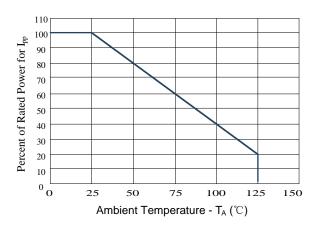


Figure3: Pulse Waveform

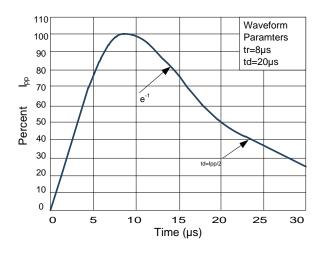
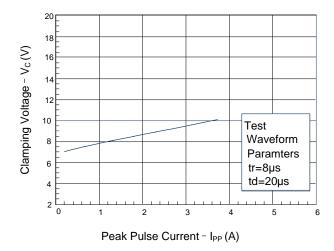
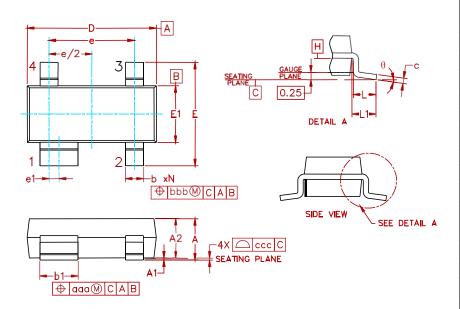


Figure 4: Clamping Voltage vs.lpp



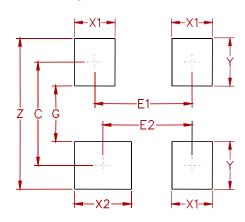


## **PACKAGEMECHANICALDATA**



	Inches			Millimeters			
Symbol	Min. Nom.		Max.		Nom.	Max.	
Α	0.031	-	0.048	0.80	-	1.22	
A1	0.000	-	0.008	0.013	-	0.15	
A2	0.020	0.035	0.042	0.75	0.90	1.07	
b	0.011	-	0.020	0.30	-	0.51	
b1	0.029	ı	0.037	0.76	1	0.94	
С	0.003	ı	0.008	0.08	-	0.20	
D	0.110	0.114	0.120	2.80	2.90	3.04	
E	0.082	0.093	0.104	2.10	2.37	2.64	
E1	0.047	0.051	0.055	1.20	1.30	1.40	
е	0.075			1.92 BSC			
e1	0.008			0.20 BSC			
L	0.015	0.020	0.024	0.40	0.50	0.60	
L1	(0.021)			(0.54)			
N	4			4			
θ	0°	-	8°	0°	-	8°	
aaa	0.006			0.15			
bbb	0.008			0.20			
ССС	0.004			0.10			

# **Suggested Pad Layout**



## **Order information**

Orderable Device	Package	Packing Option
SP0503BAHTG-MS	SOT-143	3000PCS



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